# Sensors

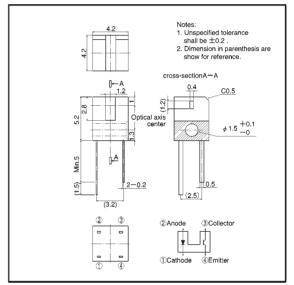
# Photointerrupter, double-layer mold type RPI-131

The RPI-131 is an ultra-small size, doulble-layer photointerrupter.

Applications
Optical control equipment
Cameras
Floppy disk drives

#### Features

- 1) Ultra-small.
- 2) Minimal influence from stray light.
- 3) Low collector-emitter saturation voltage.



#### •Absolute maximum ratings (Ta = $25^{\circ}$ C)

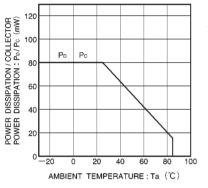
Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	lf	50	mA
	Reverse voltage	VR	5	V
Inpl	Power dissipation	PD	80	mW
Output (photo- (transistor)	Collector-emitter voltage	VCEO	30	V
	Emitter-collector voltage	VECO	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25~+85	ĉ
Storage temperature		Tstg	-40~+100	ĉ

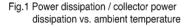
## External dimensions (Units: mm)

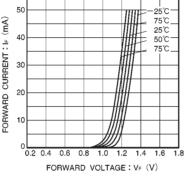
Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
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Input charac- teristics	Forward voltage	VF		1.3	1.6	V	IF=50mA
	Reverse current	IR	—	—	10	μA	V <sub>R</sub> =5V
Output charac- teristics	Dark current	ICEO	—	—	0.5	μA	V <sub>CE</sub> =10V
	Peak sensitivity wavelength	λp	—	800	—	nm	—
Transfer charac- teristics	Collector current	lc1	0.7	—	—	mA	Vce=5V, Ir=20mA
		Ic2	0.2	—	—	mA	Vc∈=5V, I⊧=5m
	Collector-emitter saturation voltage	VCE(sat)	_	_	0.3	v	I⊧=20mA, Ic=0.3mA
	Response time	tr∙tf	_	10	_	μs	Vcc=5V, I⊧=20mA, RL=100Ω

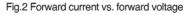
## •Electrical and optical characteristics (Ta = $25^{\circ}$ C)

Electrical and optical characteristic curves









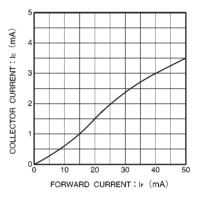


Fig.3 Collector current vs. forward current

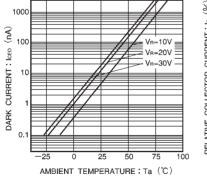


Fig.4 Dark current vs. ambient temperature

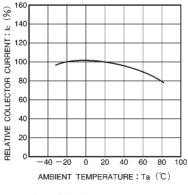


Fig.5 Relative output vs. ambient temperature

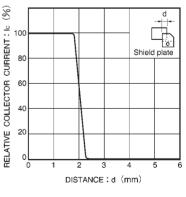
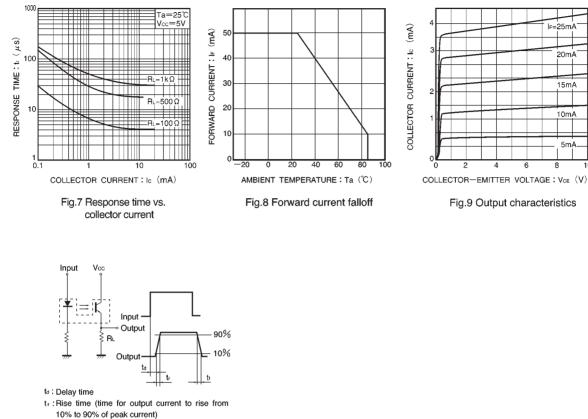


Fig.6 Relative output current vs. distance



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tr : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.10 Response time measurement circuit

